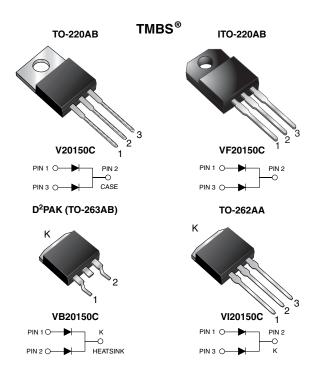
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Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.59 \text{ V}$ at $I_F = 5 \text{ A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 10 A					
V _{RRM}	150 V					
I _{FSM}	120 A					
V _F at I _F = 10 A	0.69 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES





- · Low forward voltage drop, low power losses
- · High efficiency operation

- **e**3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D^2PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER			V20150C	VF20150C	VB20150C	VI20150C	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	150				V	
Maximum average forward rectified current per device			20				^	
(fig. 1)	per diode	I _{F(AV)}	10				A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			120			Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode			70		mJ			
Peak repetitive reverse current at t_p = 2 $\mu s,1$ kHz, T_J = 38 $^{\circ}C$ \pm 2 $^{\circ}C$ per diode			0.5			Α		
Voltage rate of change (rated V _R)			10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500			V		
Operating junction and storage temperature range			-55 to +150			°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	$I_R = 1.0 \text{ mA}$	T _A = 25 °C	V_{BR}	150 (minimum)	-	V		
Instantaneous forward voltage per diode (1)	I _F = 5 A	- T _A = 25 °C	- V _F	0.79	-	V		
	I _F = 10 A			1.05	1.20			
	I _F = 5 A	T _A = 125 °C		0.59	-			
	I _F = 10 A			0.69	0.75			
Reverse current per diode (2)	V _R = 100 V	T _A = 25 °C	I _R	1.3	-	μΑ		
	V _R = 100 V	T _A = 125 °C		1.2	-	mA		
	V _R = 150 V	T _A = 25 °C		-	150	μA		
	v _R = 150 v	T _A = 125 °C		3	15	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V20150C	VF20150C	VB20150C	VI20150C	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.8	5.0	2.8	2.8	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V20150C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF20150C-E3/4W	1.75	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB20150C-E3/4W	1.39	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB20150C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI20150C-E3/4W	1.45	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

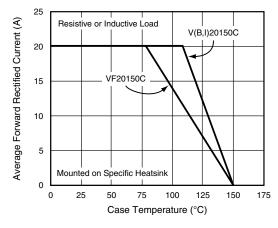


Fig. 1 - Maximum Forward Current Derating Curve

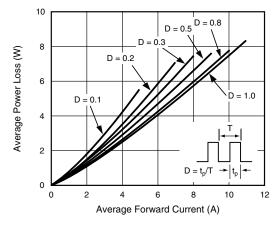


Fig. 2 - Forward Power Loss Characteristics Per Diode

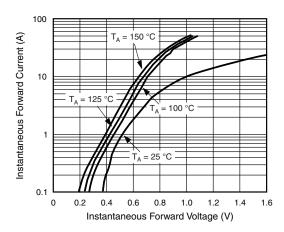


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

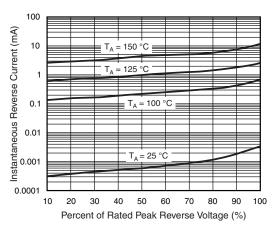


Fig. 4 - Typical Reverse Characteristics Per Diode

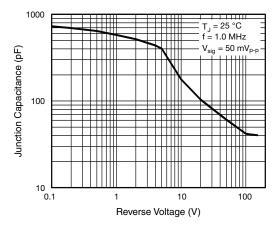


Fig. 5 - Typical Junction Capacitance

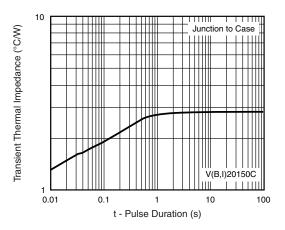


Fig. 6 - Typical Transient Thermal Impedance Per Diode

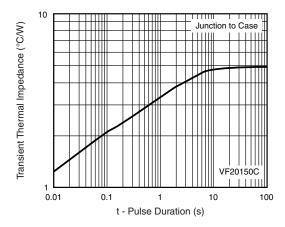
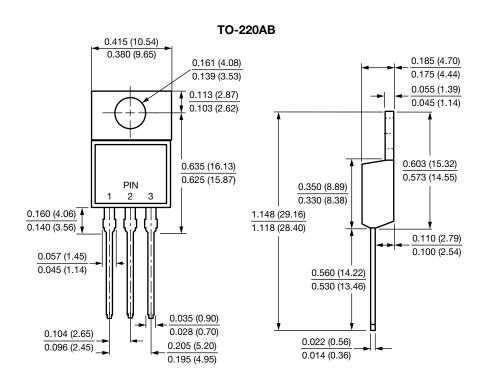


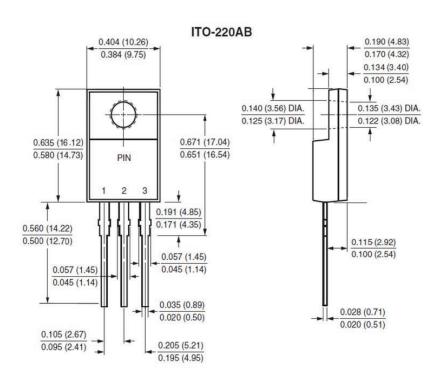
Fig. 7 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

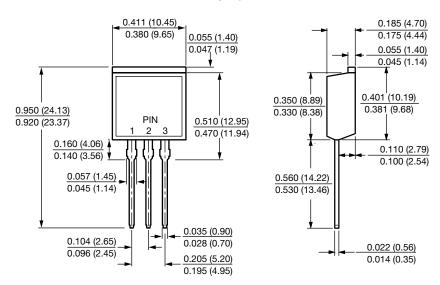




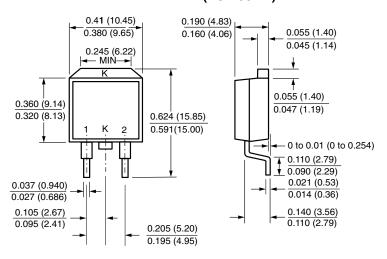
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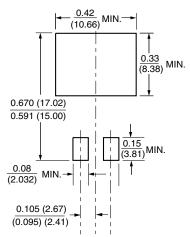
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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